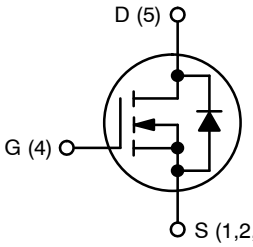
MOSFET - Power, Single N-Channel, STD Gate, SO8FL

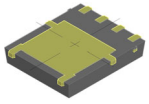
80 V, 6.2 mΩ, 71 A

NVMFWS6D2N08X

$V_{(BR)DSS}$	$R_{DS(ON)}$ MAX	I_D MAX
80 V	6.2 mΩ @ 10 V	71 A



N−CHANNEL MOSFET



DFNW5 (SO−8FL)
CASE 507BA



6D2N8W = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week
ZZ = Assembly Lot Code

Features

- Low Q_{RR}, Soft Recovery Body Diode
- Low $R_{DS(on)}$ to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- AEC−Q101 Qualified and PPAP Capable
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Synchronous Rectification (SR) in DC−DC and AC−DC
- Primary Switch in Isolated DC−DC Converter
- Motor Drives
- Automotive 48 V System

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Parameter		Symbol	Value	Unit
Drain−to−Source Voltage		V_{DSS}	80	V
Gate−to−Source Voltage	DC	V_{GS}	±20	V
Continuous Drain Current (Note 1)	T_C = 25°C	I_D	71	A
	T_C = 100°C		50	
Power Dissipation (Note 1)	T_C = 25°C	P_D	68	W
Pulsed Drain Current	T_C = 25°C, t_p = 100 μs	I_{DM}	265	A
Pulsed Source Current (Body Diode)		I_{SM}	265	A
Operating Junction and Storage Temperature Range		T_J, T_{STG}	−55 to +175	°C
Source Current (Body Diode)		I_S	102	A
Single Pulse Avalanche Energy (Note 3) (I_{PK} = 28 A)		E_{AS}	39	mJ
Lead Temperature for Soldering Purposes (1/8″ from case for 10 s)		T_L	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
2. Actual continuous current will be limited by thermal and electromechanical application board design.
3. E_{AS} of 39 mJ is based on started T_J = 25°C, I_{AS} = 28 A, V_{DD} = 64 V, V_{GS} = 10 V, 100% avalanche tested

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 5 of this data sheet.

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THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction−to−Case (Note 5)	$R_{\theta JC}$	2.22	°C/W
Thermal Resistance, Junction−to−Ambient (Notes 4, 5)	$R_{\theta JA}$	39	

4. Surface−mounted on FR4 board using 1 in^2, 1 oz Cu pad.
5. $R_{\theta JA}$ is determined by the user's board design.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Drain−to−Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS} = 0 V, I_D = 1 mA	80			V
Drain−to−Source Breakdown Voltage Temperature Coefficient	$\Delta V_{(BR)DSS}/\Delta T_J$	I_D = 1 mA. Referenced to 25°C		31.7		mV/°C
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 80 V, T_J = 25°C			1	μA
		V_{DS} = 80 V, T_J = 125°C			250	
Gate−to−Source Leakage Current	I_{GSS}	V_{GS} = 20 V, V_{DS} = 0 V			100	nA
ON CHARACTERISTICS						
Drain−to−Source On Resistance	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 15 A		5.4	6.2	mΩ
Gate Threshold Voltage	$V_{GS(TH)}$	V_{GS} = V_{DS}, I_D = 75 μA	2.4		3.6	V
Gate Threshold Voltage Temperature Coefficient	$\Delta V_{GS(TH)}/\Delta T_J$	V_{GS} = V_{DS}, I_D = 75 μA		−7.5		mV/°C
Forward Transconductance	g_{FS}	V_{DS} = 5 V, I_D = 15 A		48		S
CHARGES, CAPACITANCES & GATE RESISTANCE						
Input Capacitance	C_{ISS}	V_{GS} = 0 V, V_{DS} = 40 V, f = 1 MHz		1330		pF
Output Capacitance	C_{OSS}			390		
Reverse Transfer Capacitance	C_{RSS}			6		
Output Charge	Q_{OSS}			28		
Total Gate Charge	$Q_{G(TOT)}$	V_{GS} = 10 V, V_{DD} = 40 V; I_D = 15 A		19		nC
Threshold Gate Charge	$Q_{G(TH)}$			4		
Gate−to−Source Charge	Q_{GS}			6		
Gate−to−Drain Charge	Q_{GD}			3.0		
Gate Plateau Voltage	V_{GP}			4.7		V
Gate Resistance	R_G	f = 1 MHz		1.5		Ω
SWITCHING CHARACTERISTICS						
Turn−On Delay Time	$t_{d(ON)}$	Resistive Load, V_{GS} = 0/10 V, V_{DD} = 64 V, I_D = 15 A, R_G = 2.5 Ω		16		ns
Rise Time	t_r			6		
Turn−Off Delay Time	$t_{d(OFF)}$			24		
Fall Time	t_f			5		
SOURCE−TO−DRAIN DIODE CHARACTERISTICS						
Forward Diode Voltage	V_{SD}	V_{GS} = 0 V, I_S = 15 A, T_J = 25°C		0.82	1.2	V
		V_{GS} = 0 V, I_S = 15 A, T_J = 125°C		0.66		
Reverse Recovery Time	t_{RR}	V_{GS} = 0 V, dI/dt = 1000 A/μs, I_S = 15 A, V_{DD} = 64 V		18		ns
Charge Time	t_a			9		
Discharge Time	t_b			9		
Reverse Recovery Charge	Q_{RR}			88		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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TYPICAL CHARACTERISTICS

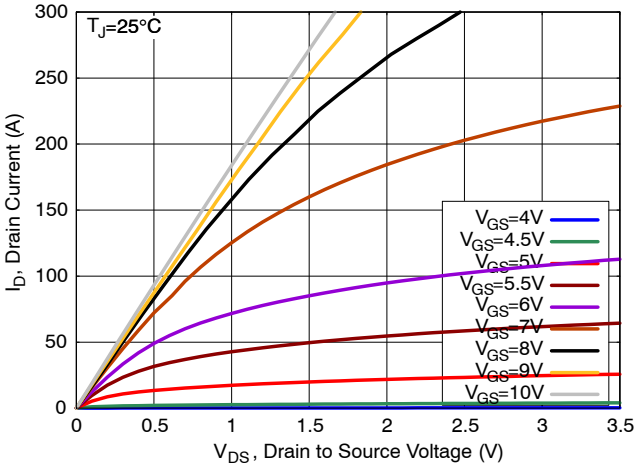

Figure 1. On−Region Characteristics

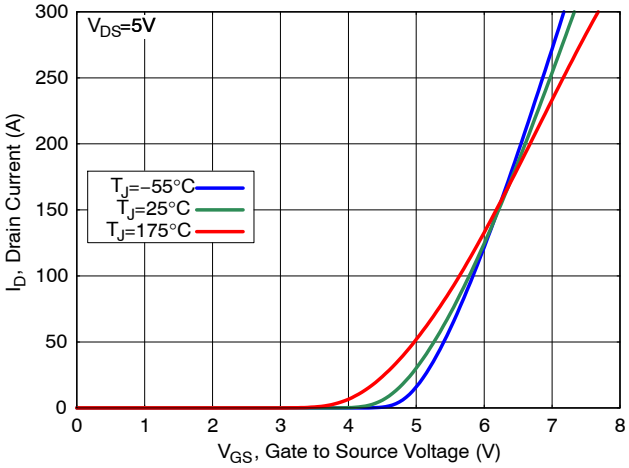

Figure 2. Transfer Characteristics

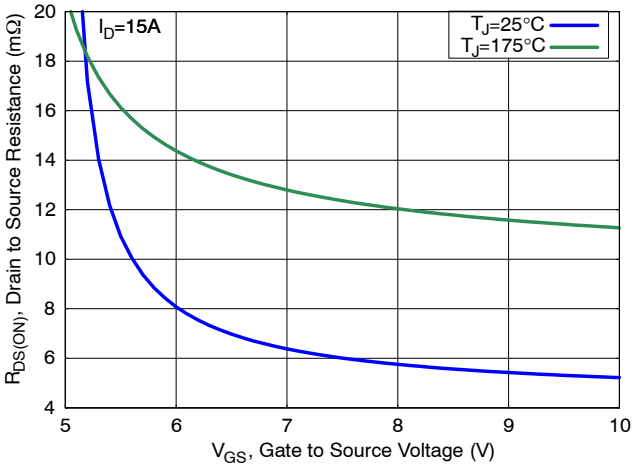

Figure 3. On−Resistance vs. Gate Voltage

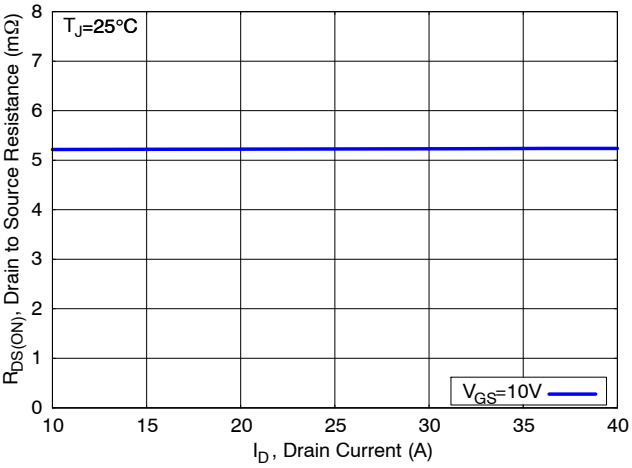

Figure 4. On−Resistance vs. Drain Current

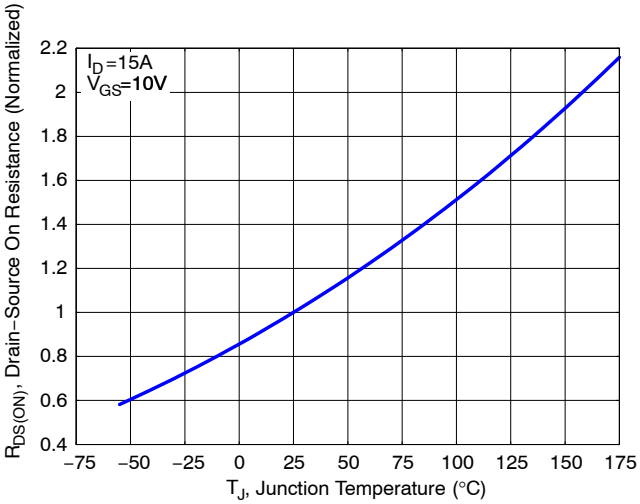

Figure 5. Normalized ON Resistance vs. Junction Temperature

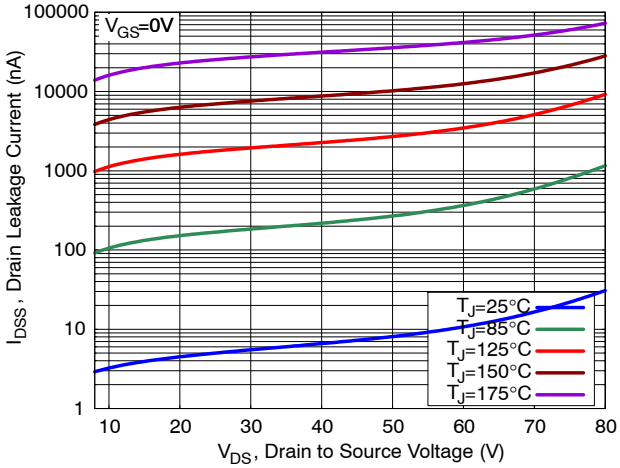

Figure 6. Drain Leakage Current vs. Drain Voltage

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TYPICAL CHARACTERISTICS (continued)

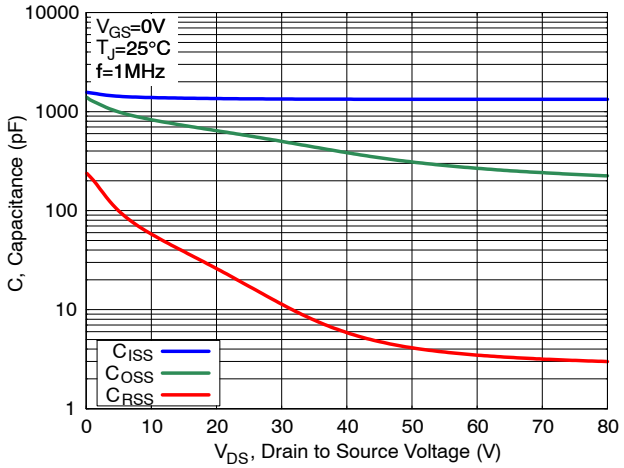

Figure 7. Capacitance Characteristics

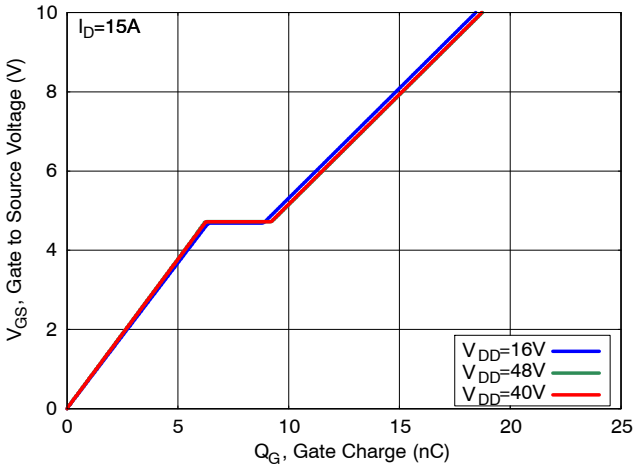

Figure 8. Gate Charge Characteristics

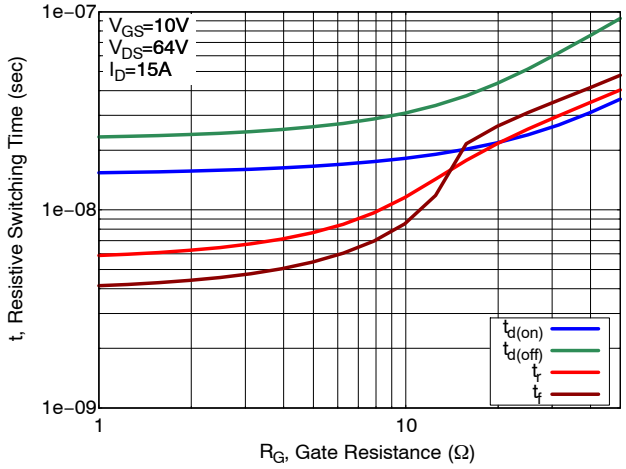

Figure 9. Resistive Switching Time Variation vs. Gate Resistance

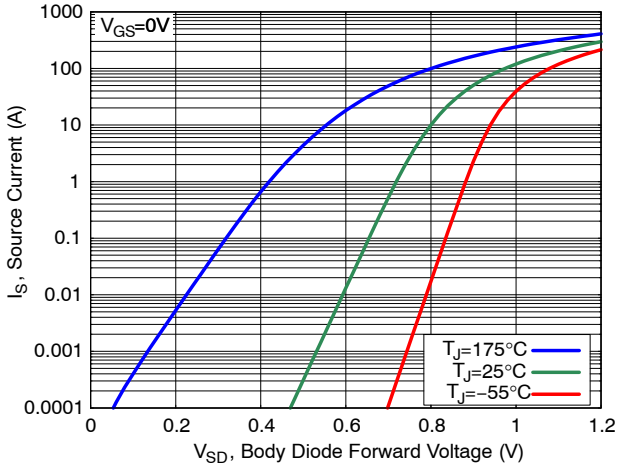

Figure 10. Diode Forward Characteristics

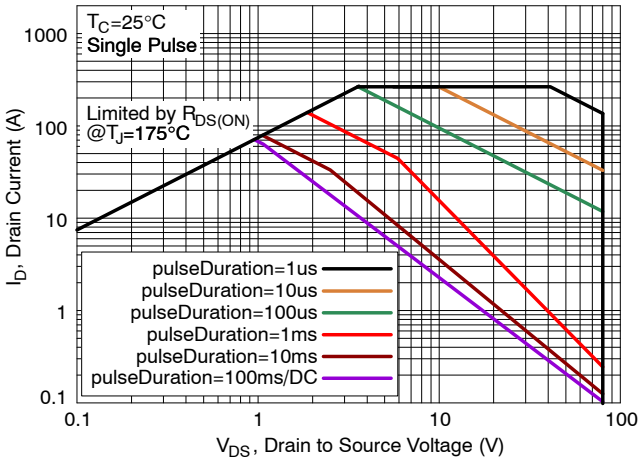

Figure 11. Safe Operating Area (SOA)

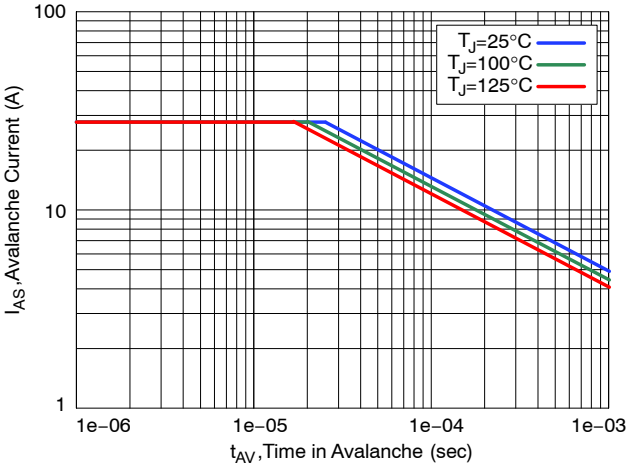

Figure 12. Avalanche Current vs. Pulse Time (UIS)

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TYPICAL CHARACTERISTICS (continued)

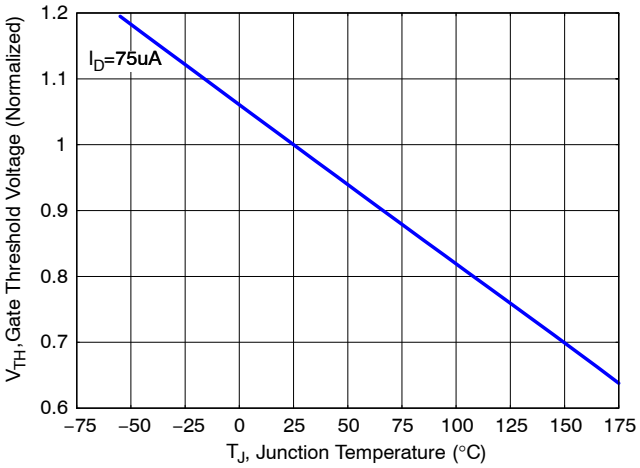

Figure 13. Gate Threshold Voltage vs. Junction Temperature

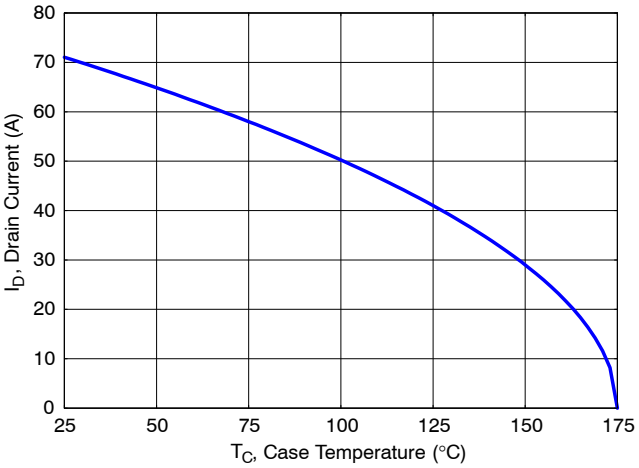

Figure 14. Maximum Current vs. Case Temperature

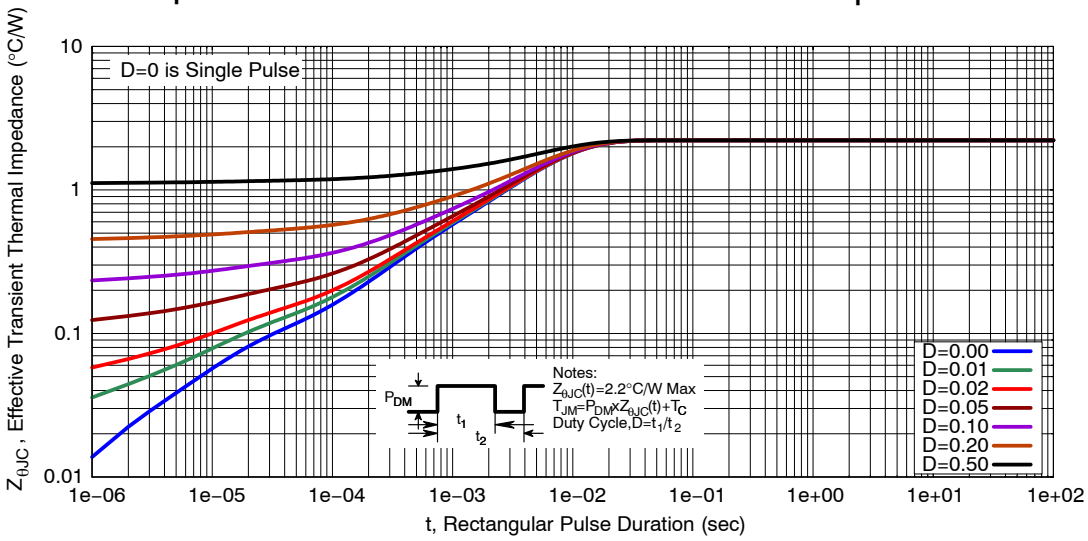

Figure 15. Transient Thermal Response

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping†
NVMFWS6D2N08XT1G	6D2N8W	DFNW5 (Pb−Free)	1500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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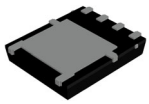
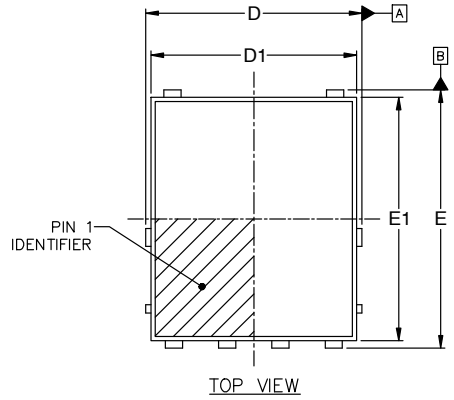
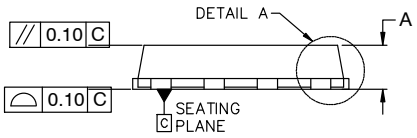
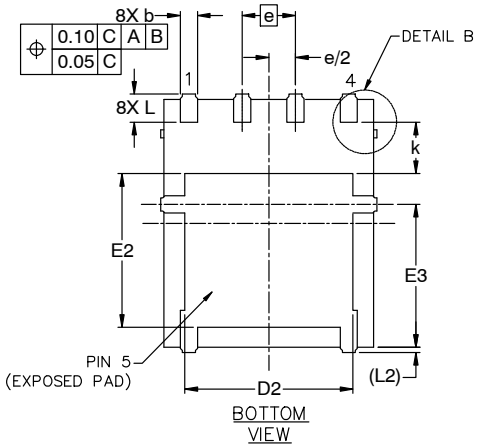


DFNW−5 4.90x5.90x1.00, 1.27P
CASE 507BA
ISSUE D

DATE 05 OCT 2026

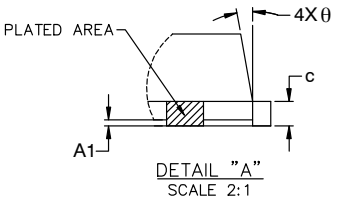


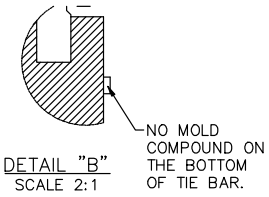




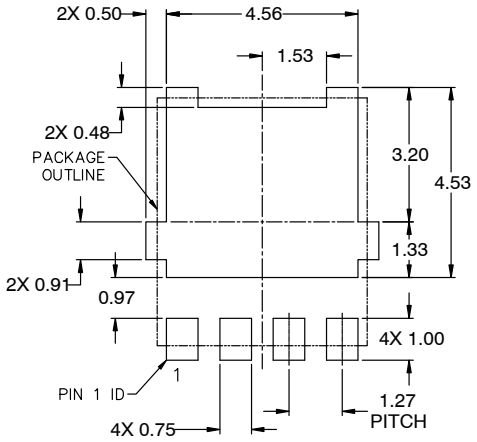
NOTES:

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5M−2018.
2. ALL DIMENSIONS ARE IN MILLIMETERS.
3. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
4. THIS PACKAGE CONTAINS WETTABLE FLANK DESIGN FEATURES TO AID IN FILLET FORMATION ON THE LEADS DURING MOUNTING.





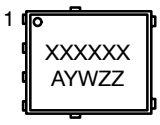
DIM	MILLIMETERS		
	MIN	NOM	MAX
A	0.90	1.00	1.10
A1	0.00	−−−	0.05
b	0.33	0.41	0.51
c	0.23	0.28	0.33
D	5.00	5.15	5.30
D1	4.70	4.90	5.10
D2	3.80	4.00	4.20
E	6.00	6.15	6.30
E1	5.70	5.90	6.10
E2	3.45	3.65	3.85
E3	3.00	3.40	3.80
e	1.27 BSC		
k	1.20	1.35	1.50
L	0.51	0.57	0.71
L2	0.15 REF.		
θ	0°	6°	12°



RECOMMENDED MOUNTING FOOTPRINT*

*FOR ADDITIONAL INFORMATION ON OUR Pb−FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ONSEMI SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXXX = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week
ZZ = Lot Traceability

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot " ▪", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**DFNW−5 4.90x5.90x1.00, 1.27P**	**PAGE 1 OF 1**

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Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

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Entegreden kapasitöre tüm elektronik komponent kategorileri.

Kategorilere göz atın

Üreticiler

Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

Üreticileri görün

Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

Teklif isteyin

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